NSN 5961-00-410-8510

Diode Semiconductor Device - Page 1 of 1



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Inclosure Material:
Metal
Overall Length:
0.375 inches
Mounting Facility Quantity:
1
Mounting Method:
Threaded stud
Overall Width Across Flats:
0.500 inches
Thread Size:
0.190 inches
Semiconductor Material:
Silicon
Voltage Rating In Volts Per Characteristic:
100.0 reverse voltage, peak
Current Rating Per Characteristic:
200.00 milliamperes source cutoff current absolute
Power Rating Per Characteristic:
10.0 watts small-signal input power, common-collector preset
Maximum Operating Tempurature Per Measurement Point:
100.0 degrees celsius ambient air
Thread Series Designator:
Unf
Terminal Type And Quantity:
1 tab, solder lug and 1 threaded stud
Shelf Life:
N/a
Unit Of Measure:
Demilitarization:
No
Fiig:
Δ110a0